

TCXOKSMD100M

Temperature Controlled Crystal Oscillator

Features

Frequency 100 MHz
6 dBm min. 50 ohm sine wave output
Less than +/- 1 ppm stability
-40C to 85C
Surface Mount Package
-150 dBc/Hz typical Noise Floor

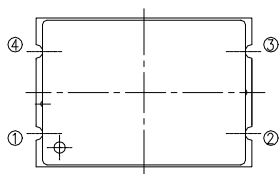
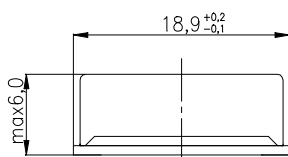
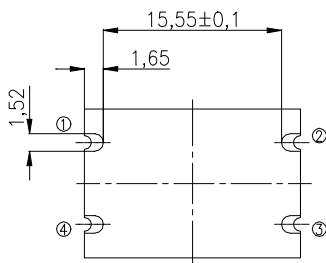
Typical Applications

Mobile Radio, Weather Radar
Frequency Reference for Low Noise Synthesizers

Description

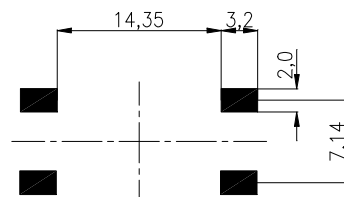
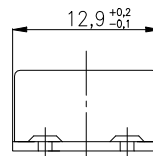
The TCXOKSMD100M employs low noise / low jitter temperature compensation techniques with 50-ohm sine wave output and less than 1 ppm temperature stability at 100 MHz operating frequency. A typical noise floor level at the 10 KHz offset is -150 dBc/Hz.

Physical Dimensions



Pin Connections

1. Control voltage V_C
2. Ground, case
3. RF-output
4. Supply voltage V_S



All Dimensions in mm

TCXOKSMD100M

Temperature Controlled Crystal Oscillator

Specification

TCXO Specification	Sym.	Condition	Value			Unit	Note
			Min.	Typ.	Max.		
Operational Frequency Range	f_0			100		MHz	
50 ohm Sine-wave ONLY	Level	L	6			dBm	
	Load Resistance	RL		50		ohm	
Power supply							
Voltage	Vcc		4.750	5.000	5.250	V	
Current consumption	Icc				40	mA	
Frequency control*							
Control voltage range	Vc		0.5	2.5	4.5	V	
Tuning range Slope			+/- 14			PPM	
Vc Input Impedance			50			Kohm	
Frequency stability							
vs. temperature		-40°C to +85°C, ref 25°C	-1.0		+1.0	ppm	
vs. 5% change in supply voltage		ref Vcc typ.	-0.100		+0.100	ppm	
Tolerance at 25C		Initial Tolerance after reflow	-3.0		+3.0	ppm	Vcontrol = 2.5 volts
SSB Phase noise @ 100 MHz typical		10 Hz				dBc/Hz	
		100 Hz		-105	-98		
		1 kHz		-130	-125		
		10 kHz		-150	-145		
		100 kHz		-153	-150		
Aging	Per Year	Projected yearly aging after 30 days operation	-1.0		+1.0	ppm	
Environmental, mechanical conditions.							
Operating temperature range		-40°C to +85°C maximum range available that is standard					
Storage temperature range		-45°C to +90°C					
Mechanical shock							
Vibration							
Soldering							

Recommended Soldering Profile

